## Zibo Seno Electronic Engineering Co．，Ltd．

35A GLASS PASSIVATED BRIDGE RECTIFIER
淄博圣诺

## Features

－Glass Passivated Die Construction
－High Case Dielectric Strength of $1500 V_{\text {RMS }}$
－Low Reverse Leakage Current
－Surge Overload Rating to 350A Peak
－Ideal for Printed Circuit Board Applications
－Plastic Material－UL Flammability Classification 94V－0
－Lead Free：For RoHS／Lead Free Version

## Mechanical Data

－Case：Molded Plastic
－Terminals：Plated Leads，Solderable per MIL－STD－202，Method 208
－Polarity：Molded on Body
－Mounting：Through Hole for \＃6 Screw
－Mounting Torque： 5.0 in－lbs Maximum
－Marking：Type Number


| RS－35M |  |  |
| :---: | :---: | :---: |
| Dim | Min | Max |
| A | 24.80 | 25.20 |
| B | 14.70 | 15.30 |
| C | 4.00 Nominal |  |
| D | 17.20 | 17.80 |
| E | 0.90 | 1.10 |
| G | 7.30 | 7.70 |
| H | $3.10 \varnothing$ | $3.40 \varnothing$ |
| J | 3.30 | 3.70 |
| K | 1.50 | 1.90 |
| L | 9.30 | 9.70 |
| M | 2.50 | 2.90 |
| N | 3.40 | 3.80 |
| P | 4.40 | 4.80 |
| R | 0.60 | 0.80 |
| All Dimensions in $\mathbf{~ m m}$ |  |  |
|  |  |  |

## Maximum Ratings and Electrical Characteristics＠$T_{A}=25^{\circ} \mathrm{C}$ unless otherwise specified

Single phase，half wave， 60 Hz ，resistive or inductive load．
For capacitive load，derate current by $20 \%$ ．

| Characteristic | Symbol | $\begin{array}{\|c\|} \text { RS } \\ 35005 M \end{array}$ | $\begin{aligned} & \text { RS } \\ & 3501 \mathrm{M} \end{aligned}$ | $\begin{array}{\|c\|} \text { RS } \\ \text { 3502M } \end{array}$ | $\begin{gathered} \text { RS } \\ 3504 \mathrm{M} \end{gathered}$ | $\begin{gathered} \text { RS } \\ 3506 \mathrm{M} \end{gathered}$ | $\begin{gathered} \text { RS } \\ \text { 3508M } \end{gathered}$ | $\begin{gathered} \text { RS } \\ 3510 \mathrm{M} \end{gathered}$ | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage | $V_{\text {RRM }}$ <br> $V_{\text {RWM }}$ $V_{R}$ | 50 | 100 | 200 | 400 | 600 | 800 | 1000 | V |
| RMS Reverse Voltage | $\mathrm{V}_{\mathrm{R} \text {（RMS）}}$ | 35 | 70 | 140 | 280 | 420 | 560 | 700 | V |
| Average Forward Rectified Output Current <br> ＠ $\mathrm{T}_{\mathrm{C}}=110^{\circ} \mathrm{C}$ | lo | 35 |  |  |  |  |  |  | A |
| Non－Repetitive Peak Forward Surge Current， 8.3 ms single half－sine－wave superimposed on rated load （JEDEC method） | $I_{\text {FSM }}$ | 350 |  |  |  |  |  |  | A |
| Forward Voltage per element＠ $\mathrm{I}_{\mathrm{F}}=17.5 \mathrm{~A}$ | VFM | 1.05 |  |  |  |  |  |  | V |
| Peak Reverse Current <br> $@ T_{C}=25^{\circ} \mathrm{C}$ <br> at Rated DC Blocking Voltage <br> ＠ $\mathrm{T}_{\mathrm{C}}=125^{\circ} \mathrm{C}$ | IR | $\begin{array}{r} 2.0 \\ 500 \end{array}$ |  |  |  |  |  |  | $\mu \mathrm{A}$ |
| $\mathrm{I}^{2} \mathrm{t}$ Rating for Fusing（ t ＜8．3ms）（Note 1） | ${ }^{2} \mathrm{t}$ | 120 |  |  |  |  |  |  | $\mathrm{A}^{2} \mathrm{~s}$ |
| Typical Junction Capacitance per Element（Note 2） | $\mathrm{C}_{\mathrm{j}}$ | 55 |  |  |  |  |  |  | pF |
| Typical Thermal Resistance，Junction to Case（Note 3） | $\mathrm{R}_{\text {өJC }}$ | 1.4 |  |  |  |  |  |  | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| Operating and Storage Temperature Range | $\mathrm{T}_{\mathrm{j}}$ ，TStG | -55 to＋150 |  |  |  |  |  |  | ${ }^{\circ} \mathrm{C}$ |

## Notes：1．Non－repetitive，for $\mathrm{t}>1.0 \mathrm{~ms}$ and $<8.3 \mathrm{~ms}$ ．

2．Measured at 1.0 MHz and applied reverse voltage of 4.0 V DC．
3．Thermal resistance from junction to case per element．Unit mounted on $150 \times 150 \times 1.6 \mathrm{~mm}$ copper plate heat sink．

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Fig． 1 Forward．Current Derating Curve


NUMBER OF CYCLES AT 60 Hz
Fig． 3 Maximum Non－Repetitive Surge Current


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$\mathrm{V}_{\mathrm{R}}$ ，REVERSE VOLTAGE（V）
Fig． 4 Typical Junction Capacitance


Fig． 5 Typical Reverse Characteristics

